FFPF30UP20S

30 A, 200 V, Ultrafast Diode

The FFPF30UP20S is a ultrafast diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery $t_{rr} = 50 \text{ ns}$ (@ $I_F = 30 \text{ A}$)
- Max Forward Voltage, $V_F = 1.15 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- Reverse Voltage, V_{RRM} = 200 V
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Output Rectifiers
- SMPS, Power Switching Circuits
- Free-Wheeling Diode for Motor Application

ABSOLUTE MAXIMUM RATINGS

 $T_C = 25^{\circ}C$ unless otherwise noted

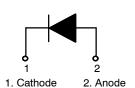
Symbol	Parameter	Rating	Unit
V _{RRM}	Peak Repetitive Reverse Voltage	200	V
V _{RWM}	Working Peak Reverse Voltage	200	V
V _R	DC Blocking Voltage	200	V
I _{F(AV)}	Average Rectified Forward Current @ T _C = 102°C	30	Α
I _{FSM}	Non-repetitive Peak Surge Current 60 Hz Single Half-Sine Wave	300	Α
T _{J,} T _{STG}	Operating Junction and Storage -65 to +175		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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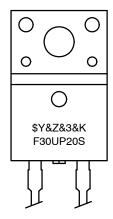
www.onsemi.com





TO-220, 2-Lead CASE 221AS

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z&3 = Data Code (Year & Week)

&K = Lot

F30UP20S = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFPF30UP20S

THERMAL CHARACTERISTICS

Symbol	Parameter	Max.	Unit
$R_{ heta JC}$	Maximum Thermal Resistance, Junction to Case	3.0	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF30UP20STU	F30UP20S	TO-220F-2L	Tube	N/A	N/A	50

ELECTRICAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Parameter	Conditions		Min.	Тур.	Max.	Unit
V _F (Note 1)	I _F = 30 A I _F = 30 A	T _C = 25°C T _C = 125°C	- -	-	1.15 1.0	V
I _R (Note 1)	V _R = 200 V V _R = 200 V	T _C = 25°C T _C = 125°C	-	1 1	100 500	μ Α μ Α
t _{rr}	$\begin{array}{c} I_F = 1 \text{ A, di}_F/\text{dt} = 100 \text{ A/}\mu\text{s, V}_{CC} = 30 \text{ V} \\ I_F = 30 \text{ A, di}_F/\text{dt} = 200 \text{ A/}\mu\text{s, V}_{CC} = 130 \text{ V} \end{array}$	T _C = 25°C T _C = 25°C	- -	-	40 50	ns ns
t _a t _b Q _{rr}	$I_F = 30 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A}/\mu\text{s}, \text{ V}_{CC} = 130 \text{ V}$	T _C = 25°C T _C = 25°C T _C = 25°C	- - -	22 14 67	- - -	ns ns nC
W _{AVL}	Avalanche Energy (L = 40 mH)		20	-	_	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse Width = 300 μs, Duty Cycle = 2%

Test Circuit and Waveforms

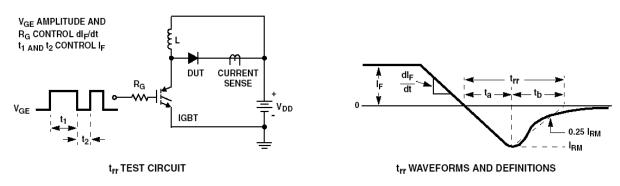


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

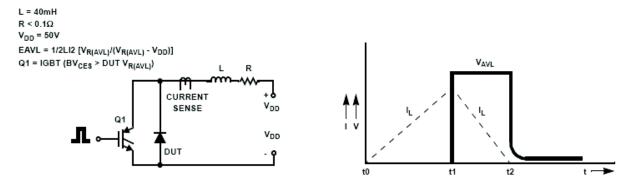


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

FFPF30UP20S

TYPICAL CHARACTERISTICS

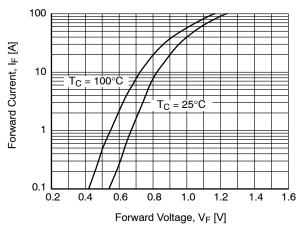


Figure 3. Typical Forward Voltage Drop

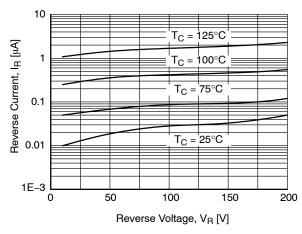


Figure 4. Typical Reverse Current

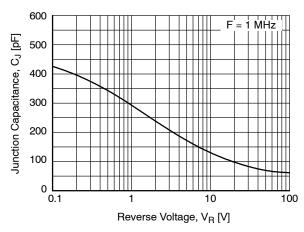


Figure 5. Typical Junction Capacitance

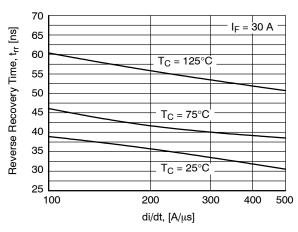


Figure 6. Typical Reverse Recovery Time

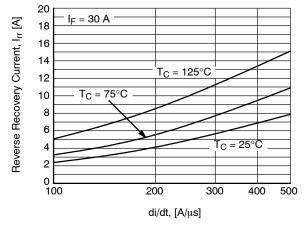


Figure 7. Typical Reverse Recovery Current

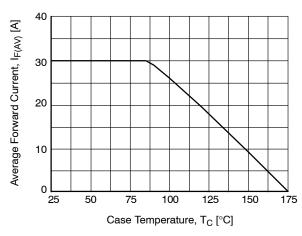


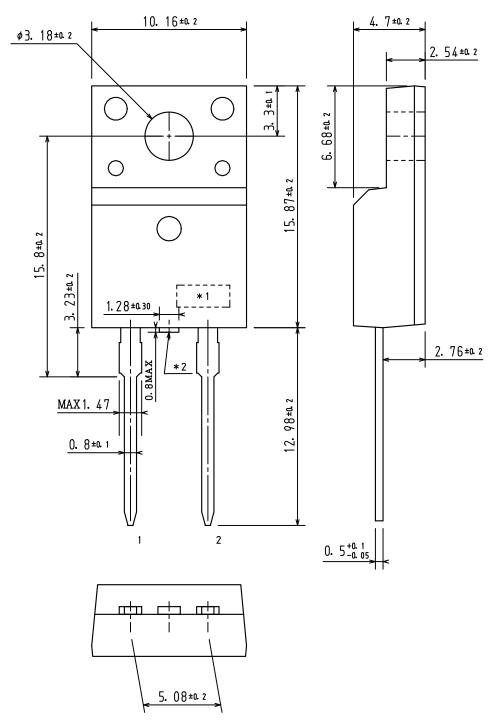
Figure 8. Forward Current Deration Curve





TO-220 Fullpack, 2-Lead / TO-220F-2FS CASE 221AS ISSUE O

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